Structure and Electric Conductivity of Mixed Electronic–Ionic Bi₂O₃-Li₂O-V₂O₅-B₂O₃ Glass System

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Abstract: In the present study, semiconducting glasses with composition xBi₂O₃-(20-x)Li₂O-20V₂O₅-60B₂O₃ (0 ≤ x ≤ 15) mol % have been prepared by the conventional melt quenching technique. The glassy state of the as prepared samples is characterized using X-ray diffraction (XRD). The density and molar volume of the investigated glass system increase with increasing Bi₂O₃ content. The infrared spectra of these glasses are recorded over a continuous spectral range (400-4000 cm⁻¹) as an attempt to study their structure systematically. FT-IR spectroscopy data reveal that B₂O₃ and Bi₂O₃ behave as network formers and incorporated in the vitreous network as [BO₃], [BO₄], [BiO₃], [BiO₄], also V₂Os incorporated in the vitreous network as [VO₃] and [VO₄] structural units. Also it is found that the number of non-bridging oxygen ions (NBOIs) increases with increasing Bi₂O₃ content. The measured DC conductivity, σdc, increases and the activation energy decreases at low temperature region at the same time the conductivity at high temperature region decreases and the activation energy increases with increasing Bi₂O₃ content. DC conductivity at room temperature (303 K) is typically 10⁻⁷-10⁶ (Ω⁻¹m⁻¹) with activation energies at low and high temperature regions 0.34-0.17 (eV) and 0.80-0.64 (eV) respectively. Debye temperature, θD, increases with increasing Bi₂O₃ content with typical values 768-860 K.

Keywords: Oxide glasses; Density; IR spectroscopy; DC conductivity

1 Introduction

The semiconducting oxide glasses containing heavy metal oxide (HMO) such as bismuth oxide (Bi₂O₃) have received increased interest because of their possible applications in the field of glass ceramics, layers for optical and optoelectronic devices, thermal and mechanical sensors and reflecting windows [1-4]. Also borate glasses containing unconventional Bi₂O₃ as network former possess high refractive index, high optical basicity, extended far IR transmission and high non-linear optical susceptibility [3-5].

The interest for the investigated glassy system is determined by the presence of two network forming oxides, the classical B₂O₃ and unconventional Bi₂O₃ in addition to the presence of transition metal oxide (TMO) V₂O₅ and alkali oxide Li₂O. It was known that B₂O₃ is one of the most common glass formers. According to Krogh-Moe [6] the structure of vitreous B₂O₃ consists of a random network of boroxol rings and [BO₃] triangles connected by B-O-B linkages. At the same time Bi₂O₃ may build a glass network of [BiO₃] and [BiO₄] polyhedra over a wide compositional range [7, 8]. An important class of glasses is the one which containing transition metal oxides (TMOs) such as V₂O₅ which exhibit semiconducting properties due to the existence of transition metal ions (TMIs) in more than one valence state (V⁴⁺ and V⁵⁺) [9, 10]. The electron-phonon interaction in these glasses is strong enough to form small polaron, and the electrical conduction process occurs by the hopping of small polarons between different valence states as proposed by Austin and Mott [11]. Recent studies showed that the electric conduction in glasses containing V₂O₅ (TMOs) may be attributed to small polarons hopping (SPH) which occurs from the low valance states (V⁴⁺) to the neighboring high valance states (V⁵⁺) [12-16]. The present work has been carried out to study the effect of partial replacement of Li₂O by Bi₂O₃ on the structure and electric conduction of the as prepared semiconducting glass samples of composition xBi₂O₃-(20-x)Li₂O-20V₂O₅-60B₂O₃ (0 ≤ x ≤ 15) mol %.

2 Experimental Procedures

2.1 Sample Preparation and density measurement

The semiconducting glass system having the general chemical formula xBi₂O₃-(20-x)Li₂O-20V₂O₅-60B₂O₃ (x = 0, 5, 10, and 15 mol %) have been prepared by the melt quenching technique. The preparation is carried out by melting homogeneous mixtures of reagent grade H₃BO₃, V₂O₅, Bi₂O₃ and Li₂CO₃ (with purity not less than 99.8 %).
in porcelain crucibles using an electric furnace at 1000 °C for 2 h. The melts are quenched between two pre-cooled copper plates to form (2cmx2cmx2mm) glass samples.

The glassy states of the as-prepared samples of the investigated system are detected using a Philips X-ray diffractometer PW/1710 with Ni filtered, Cu Ka radiation (λ = 1.542 Å) powered at 40 (kV) and 30 (mA) (Figure 1). The room temperature densities, ρ, of the as prepared glass samples are measured using the suspension weight method based on Archimedes principle using toluene as an immersion liquid whose density is (0.868 g/cm³).

![XRD patterns](image)

**Fig. 1.** XRD patterns for the as prepared xBi₂O₃-(20-x)Li₂O-20V₂O₅-60B₂O₃ (x = 0, 5, 10 and 15 mol %) system.

### 2.2 FT-IR measurements

In order to investigate the local order characterizing vitreous materials Fourier transform infrared (FT-IR) spectroscopy is a very sensitive and one of the most used spectroscopic methods. The infrared (IR) absorption spectra of the glasses in the wavenumber range (from 4000 to 400 cm⁻¹) with a resolution of 4 cm⁻¹ are measured at room temperature by an infrared spectrophotometer type JASCO, FT/IR-430 (Japan).

### 2.3 DC conductivity measurements

The DC conductivity, σdc, of the as-quenched glasses is measured at temperatures between 300 and 600 K and under a constant DC voltage. For electric measurements the as prepared glass samples are polished to obtain optically parallel surfaces of 1.5 (mm) thickness. In order to achieve the best electrical contact between the glass samples and the electrodes of the sample holder the measurements are carried out on the silver paste coated pellets. The value of the current at different temperatures is measured using a Picoammeter (Keithley 485 Autoranging Picoammeter) and the I-V characteristic between electrodes is verified.

### 3 Results and Discussion

#### 3.1 Density and molar volume

The variation in the density with composition in oxide glass system can be expressed in terms of apparent volume occupied by 1g atom of oxygen (molar volume Vₘ) which can be calculated from the density and composition using the following formula [17]:

\[
V_m = \frac{\sum (n_i M_i)}{\rho}
\]

where, Mᵢ, is the molecular weight of oxide, nᵢ, is the molar fraction and, ρ, is the density of the sample. Fig. 2a shows the variation of the measured room temperature density, ρ, of the as prepared xBi₂O₃-(20-x)Li₂O-20V₂O₅-60B₂O₃ (x = 0, 5, 10 and 15 mol %) glass samples. Fig. 2b shows the variation of the molar volume, Vₘ, of the investigated glassy system as a function of Bi₂O₃ content. The relative error in the density measurements is about ±0.01 (g/cm³). It is found that the density and molar volume increase with increasing Bi₂O₃ content. This may be due to the higher molecular weight of Bi₂O₃ when compared to Li₂O.

This is not the general behavior which may expect for the density and molar volume. Where the general behavior should show opposite behavior to each other; but in the investigated glasses the behavior is different. This behavior may be attributed to that, the rate of increasing in molecular weight, Mᵢ, is greater than the rate of increasing in density, ρ, (eq. 1). The same behavior for, ρ, and, Vₘ, was found earlier for many semiconducting glass systems containing Bi₂O₃ [17-21].

![Density and molar volume](image)

**Fig. 2.** Density and molar volume of the xBi₂O₃-(20-x)Li₂O-20V₂O₅-60B₂O₃ (x = 0, 5, 10 and 15 mol %) glass samples as a function of Bi₂O₃ content.
3.2 Infrared spectral studies

Table 1. Deconvolution parameters of the infrared spectra of $\text{xBi}_2\text{O}_3-(20-x)\text{Li}_2\text{O}-20\text{V}_2\text{O}_5-60\text{B}_2\text{O}_3$ (x = 0, 5, 10 and 15 mol %) glasses. C is the component band center and A is the relative area (%) of the component band.

<table>
<thead>
<tr>
<th>x (mol %)</th>
<th>C (cm$^{-1}$)</th>
<th>A (%)</th>
<th>C (cm$^{-1}$)</th>
<th>A (%)</th>
<th>C (cm$^{-1}$)</th>
<th>A (%)</th>
<th>C (cm$^{-1}$)</th>
<th>A (%)</th>
<th>Assignments</th>
</tr>
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<tbody>
<tr>
<td>0</td>
<td>443</td>
<td>1.3</td>
<td>448</td>
<td>1.3</td>
<td>455</td>
<td>49.4</td>
<td>459</td>
<td>7.3</td>
<td>443: Vibrations of angular deformation vibration of the O-V bond.</td>
</tr>
<tr>
<td>5</td>
<td>510</td>
<td>4.6</td>
<td>521</td>
<td>6.8</td>
<td>532</td>
<td>35.4</td>
<td>541</td>
<td>8.5</td>
<td>448-459: Bi-O bond in Bi$_2$O$_3$ units, vibrations of angular deformation vibration of the O-V bond.</td>
</tr>
<tr>
<td>10</td>
<td>632</td>
<td>6.2</td>
<td>637</td>
<td>10.8</td>
<td>642</td>
<td>19.4</td>
<td>686</td>
<td>12.3</td>
<td>510: Bending vibration of BO$_3$ units.</td>
</tr>
<tr>
<td>15</td>
<td>700</td>
<td>6.7</td>
<td>702</td>
<td>11.3</td>
<td>702</td>
<td>23.5</td>
<td>700</td>
<td>13.7</td>
<td>521-541: Bi-O bond in Bi$_2$O$_3$ units, bending vibration of BO$_3$ units.</td>
</tr>
<tr>
<td>0</td>
<td>793</td>
<td>9.7</td>
<td>803</td>
<td>14.8</td>
<td>834</td>
<td>24.9</td>
<td>864</td>
<td>17.3</td>
<td>632-686: antisymmetric vibrational modes of V-O-V group.</td>
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<tr>
<td>5</td>
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<td>14.2</td>
<td>957</td>
<td>23.8</td>
<td>974</td>
<td>30.8</td>
<td>996</td>
<td>8.4</td>
<td>700-702: Bending vibration of B-O-B in BO$_3$ triangles, antisymmetric vibrational modes of V-O-V group.</td>
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<tr>
<td>10</td>
<td>1129</td>
<td>10.3</td>
<td>1118</td>
<td>15.2</td>
<td>1108</td>
<td>33.7</td>
<td>1099</td>
<td>5.4</td>
<td>793: B-O bond stretching of tetrahedral BO$_3$ units.</td>
</tr>
<tr>
<td>15</td>
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<td>4.9</td>
<td>1244</td>
<td>7.4</td>
<td>1235</td>
<td>19.8</td>
<td>1228</td>
<td>7.5</td>
<td>803-861: B-O bond stretching of tetrahedral BO$_3$ units, Bi-O bond in the Bi$_2$O$_3$ polyhedra.</td>
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<tr>
<td>0</td>
<td>1327</td>
<td>5.0</td>
<td>1327</td>
<td>12.8</td>
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<td>17.7</td>
<td>1320</td>
<td>7.3</td>
<td>957-996: B-O stretch in BO$_3$ units from diborate groups; Symmetric stretching vibrations of the isolated VO$_2$ group in VO$_2$ polyhedra, V-O bond of VO$_2$ group.</td>
</tr>
<tr>
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<td>5.6</td>
<td>1399</td>
<td>11.3</td>
<td>1387</td>
<td>28.5</td>
<td>1383</td>
<td>8.3</td>
<td>1129-1099: Tetrahedral BO$_3$ borate units.</td>
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<td>1516</td>
<td>11.7</td>
<td>1504</td>
<td>14.9</td>
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<td>14.6</td>
<td>1437</td>
<td>7.1</td>
<td>1200-1600 cm$^{-1}$: Stretching vibration of B-O-B in BO$_3$ triangles only.</td>
</tr>
<tr>
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<td>1526</td>
<td>15.3</td>
<td>1520</td>
<td>13.6</td>
<td>1515</td>
<td>2.7</td>
<td>1510</td>
<td>2.3</td>
<td></td>
</tr>
</tbody>
</table>

Fig. 3. Infrared absorption spectra of the $\text{xBi}_2\text{O}_3-(20-x)\text{Li}_2\text{O}-20\text{V}_2\text{O}_5-60\text{B}_2\text{O}_3$ (x = 0, 5, 10 and 15 mol %) glass samples.

The obtained IR spectra of all the investigated glass samples are shown in Fig. 3, and the de-convolution analysis method is used to inspect the obtained IR bands where many different bands are clearly observed. These bands indicated the presence of different structural units in the glass network. Fig. 4 shows the de-convolution analysis for the IR spectra of the glass samples containing 0 and 15 mol % Bi$_2$O$_3$, as representative curves. As shown in this Figure, the result of peak de-convolution indicates a number of 13 peaks in the spectral range from 400 to 1650 cm$^{-1}$. Each individual band has its characteristic parameters such as its center (C), which is related to some type of vibration of a specific structural group, and its relative area (A), which is proportional to the concentration of that structural group. The de-convolution parameters, the band center (C) and the relative area (A) as well as the band assignment are given in Table 1. The bands around ~ 1640 cm$^{-1}$ for all the investigated glass samples are assigned to
crystal water with H-O-H bending mode. For the Bi2O3-free glass sample (x = 0 mol %) the FT-IR spectrum of vitreous glass matrix contain three major absorption bands in the wavenumber ranges of 400-800 cm\(^{-1}\), 800-1200 cm\(^{-1}\) and 1200-1600 cm\(^{-1}\). In the first wavenumber region 400-800 cm\(^{-1}\) five absorption bands are observed, at ~ 443 cm\(^{-1}\) may be attributed to vibrations of angular deformation vibration of the O-V bond, the band around ~ 510 cm\(^{-1}\) can be attributed to the borate deformation modes, such as the in-plane bending of boron-oxygen triangles [22], at ~ 632-686 cm\(^{-1}\) were assigned to the anti-symmetric vibrational modes of V-O-V group, at ~ 700-702 cm\(^{-1}\) that were assigned to combination of the bending vibration of B-O-B in BO\(_3\) triangles and anti-symmetric vibrational modes of V-O-V group [23-25] and at ~ 793 which was assigned to the B-O bond stretching of tetrahedral BO\(_4\) units [26-30].

The second wavenumber range, 800-1200 cm\(^{-1}\) contains two absorption bands at ~ 952 cm\(^{-1}\) which are due to the combination of the B-O stretching bond in BO\(_3\) units from diborate groups, symmetric stretching vibrations of the isolated VO\(_3\) group in VO\(_4\) polyhedra and V=O band of VO\(_3\) group [24, 27, 31] as well as at ~ 1129-1099 cm\(^{-1}\) which were assigned to tetrahedral BO\(_4\) borate units. The third wavenumber range, 1200-1600 cm\(^{-1}\) contains five absorption bands at ~ 1252, ~ 1327, ~ 1407, ~ 1516 and ~ 1526 cm\(^{-1}\) which were assigned to stretching vibration of B-O-B in BO\(_3\) triangles only [27-29]. From the FT-IR analysis it is found that the centers of the following absorption bands at ~ 443, ~ 510, ~ 632, ~ 793 and ~ 952 cm\(^{-1}\) are shifted to higher wavenumbers and higher intensities for the glass sample 5Bi2O3 15Li2O 20V2O5 60B2O3 (x = 5 mol %). At the same time the following absorption bands at ~ 1129, 1252, 1327, 1407, 1516 and 1526 cm\(^{-1}\) are shifted to lower wavenumbers and higher intensities.

The same absorption bands are found for the glass sample 10Bi2O3 10Li2O 20V2O5 60B2O3 (x = 10 mol %) as well, where the absorption bands in the region 400-1000 cm\(^{-1}\) are shifted to higher wavenumbers with higher intensities and the bands in the region ~ 1000-1600 cm\(^{-1}\) are shifted to lower wavenumbers with higher intensities, likewise the same behavior is found also for the glass sample with x = 15 mol % except for the bands at around ~ 952, 1129, 1516 and 1526 cm\(^{-1}\) which are shifted to lower wavenumbers with lower intensities.

The shift of the vibrational band towards the lower wavenumber is ascribed to the increase in the bond length of B-O bonds indicating the conversion of BO\(_3\) polyhedral (bridging oxygen ions) to BO\(_4\) tetrahedral unit (non-bridging oxygen ions). The increase in intensities of the vibrational bands with increasing Bi2O3 content suggests that, the non-bridging oxygens start appearing in the structure in larger number and may be form other borate groups. Also the increase in intensities of these bands may be results from some of the Bi\(^{3+}\) ions are occupying tetrahedral positions. The most important condition for the existence of Bi2O3 polyhedra is the presence of a band at ~ 834 cm\(^{-1}\) in the FT-IR spectrum [3] for the glass sample with 10 mol % Bi2O3. This means that, the absorption band at about ~ 834 cm\(^{-1}\) is a combination of BiO3 polyhedral and BO4 tetrahedral units. This band is shifted to higher wavenumber (~ 864 cm\(^{-1}\)) for the glass sample with 15 mol % Bi2O3.

For the glass samples containing 5, 10 and 15 mol % the bands from 448-459 cm\(^{-1}\) were assigned to the Bi-O bond vibrations in distorted BiO6 octahedra units in addition to vibrations of angular deformation vibration of the O-V bond [3, 32, 33]. The bands at around ~ 521-541 cm\(^{-1}\) are the overlapping of the vibrations of the Bi-O bonds in the BiO6 octahedral unit [33], with the bands of the in-plane bending vibration of BO\(_3\) units [26, 28, 30]. The absorption bands around ~ 957-996 cm\(^{-1}\) may be attributed to the overlapping of the B-O stretching band in BO\(_3\) units from diborate groups, Bi-O bond in the BiO\(_3\) polyhedra and symmetric stretching vibrations of the isolated VO\(_3\) group in VO\(_4\) polyhedra [34, 35].

Therefore, the FT-IR absorption spectra of the investigated glass system have evidenced that boron ions are incorporated as BO\(_3\) and BO\(_4\) units, a part of bismuth ions are incorporated in the glass network as BiO\(_3\) pyramidal and BiO\(_6\) octahedral units and a part of vanadium ions is incorporated in the glass network as VO\(_4\) and VO\(_3\) units.

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3.3 DC conductivity measurements

The conductivity of the investigated semiconducting oxide glass system which containing TMLs (V^{4+} & V^{5+}) as well as alkaline ions (Li⁺) and Bi^{3+} ions should be mixed i.e. electronic and ionic. The effect of temperature and the effect of the partial replacement of Li₂O by Bi₂O₃ on the DC conductivity of the glass composition xBi₂O₃-(20-x)Li₂O-20V₂O₅-60B₂O₃ (0 ≤ x ≤ 15) mol % are studied in more details. It is found that the DC conductivity of the investigated glass system obeys the well-known Arrhenius formula;

\[ \sigma_{dc} = \sigma_0 \exp[-E_{dc}/k_BT] \]  \hspace{1cm} (2)

where, \( E_{dc} \) is the activation energy for conduction, \( \sigma_0 \) is the pre-exponential factor, \( k_B \) is the Boltzmann constant and \( T \) is the absolute temperature in K. Fig. 5 shows the plot \( \ln \sigma_{dc} \) vs. \( 1000/T \) and it is found that the measured DC conductivity, \( \sigma_{dc} \), increases with increasing temperature. Also it is found that, the DC conductivity varied linearly against \( T^{-1} \) at two temperature regions. The first region is the low temperature region where \( T < \theta_B/2 \) and the second region is the high temperature region where \( T > \theta_B/2 \), indicating that, the conduction of the present system is mainly electronic in the low temperature region and mixed (electronic and ionic) in the high temperature region [36, 37] where, \( \theta_B \) is the Debye temperature. The electric conduction mechanism at the low temperature region depends mainly on the electron hopping from the lower valance states (V^{4+}) to the higher valance states (V^{5+}) of the vanadium ions [12-16]. The increases of the DC conductivity, \( \sigma_{dc} \), with increasing temperature may be attributed to the increase of the thermally activated small polarons hopping (SPH) [38, 39]. The effect of the partial replacement of Li₂O by Bi₂O₃ is studied as well (Figure 5).

Fig. 5. The DC conductivity, \( \sigma_{dc} \), of the xBi₂O₃-(20-x)Li₂O-20V₂O₅-60B₂O₃ (x = 0, 5, 10 and 15 mol %) glass samples as a function of reciprocal of temperature.

It is found that, at low temperature region the electric conductivity, \( \sigma_{dc} \), increases with increasing Bi₂O₃ content [40]. The increases of the DC conductivity with the partial replacement of Li₂O by Bi₂O₃ at low temperature region (\( T < \theta_B/2 \)) may be attributed to the increasing in the number of non-bridging oxygen ions (NBOs) and as a results increasing the open structure (i.e. the non-bridging oxygen ions) through which the charge carriers can move with higher mobility [41, 42]. These results are in a good agreement with the FT-IR results, where with increasing Bi₂O₃ content BO₃ polyhedral (bridging oxygen ions) convert to tetrahedral BO₄ (non-bridging oxygen ions). Virender Kundu et. al. reported that the formation of NBOs causes the decrease in band gap energy and as a result the DC conductivity increases with increasing Bi₂O₃ content [43]. At high temperature region where \( T > \theta_B/2 \) both Bi^{3+} and Li⁺ ions may become mobile and participate in the conduction process. It is found that the DC conductivity, \( \sigma_{dc} \), decreases with the partial replacement of Li₂O by Bi₂O₃ and this may be attributed to the lower mobility (higher ionic size) of Bi^{3+} ions compared to the higher mobility (lower ionic size) of Li⁺ ions. In addition to that, with increasing Bi₂O₃ content new bonds of Bi-O-Bi and Bi-O-V may be formed that lead to decreasing the DC conductivity [44]. Fig. 6a and b show the variation of DC conductivity as a function of Bi₂O₃ content at different temperatures (303, 352, 442 and 518 K) as representative curves. The activation energies of the investigated glass samples are determined from the slope of \( \ln \sigma_{dc} \) vs. \( 1000/T \). The activation energies are then evaluated by least square fitting method of eq. (2).

It is found that the activation energy (potential barrier) at the low temperature region decreases with increasing Bi₂O₃ content and at high temperature region it is found that the activation energy increases with increasing Bi₂O₃
content (Figure 7). The activation energies at low and high temperature regions are typically 0.34-0.17 eV and 0.64-0.80 eV respectively. Also it is found that Debye temperature, $\theta_D$, increases with increasing Bi$_2$O$_3$ content (Figure 8) with typical values 768-860 K. Good agreement is found between the FT-IR results and the measured DC conductivity. The values of the DC conductivity, $\sigma_{dc}$, at different temperatures (303, 352, 442 and 518 K) as an example, activation energies, $E_{dc}$, and Debye temperatures, $\theta_D$, of the investigated glass samples are listed in Table 2.

Fig. 6. DC conductivity of the investigated glass system as a function of Bi$_2$O$_3$ at different temperatures (303, 352, 442 and 518 K) as representative curves.

Table 2. DC conductivity, $\sigma_{dc}$, at different temperatures (303, 352, 442 and 518 K), activation energy, $E_{dc}$, and Debye temperature, $\theta_D$, of the xBi$_2$O$_3$-(20-x)Li$_2$O-20V$_2$O$_5$-60B$_2$O$_3$ (x = 0, 5, 10 and 15 mol %) glass samples.

<table>
<thead>
<tr>
<th>Bi$_2$O$_3$ mol %</th>
<th>$\sigma_{dc}$ ((\Omega^{-1} \text{ m}^{-1}))</th>
<th>$\sigma_{dc}$ ((\Omega^{-1} \text{ m}^{-1}))</th>
<th>$\sigma_{dc}$ ((\Omega^{-1} \text{ m}^{-1}))</th>
<th>$\sigma_{dc}$ ((\Omega^{-1} \text{ m}^{-1}))</th>
<th>$E_{dc}$ (eV)</th>
<th>$E_{dc}$ (eV)</th>
<th>$\theta_D/2$ (K)</th>
</tr>
</thead>
<tbody>
<tr>
<td>0</td>
<td>3.12 x 10^{-7}</td>
<td>1.65 x 10^{-4}</td>
<td>1.64 x 10^{-4}</td>
<td>3.07 x 10^{-3}</td>
<td>0.34±0.09</td>
<td>0.64±0.08</td>
<td>384</td>
</tr>
<tr>
<td>5</td>
<td>6.16 x 10^{-7}</td>
<td>1.87 x 10^{-4}</td>
<td>4.87 x 10^{-6}</td>
<td>8.5 x 10^{-4}</td>
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<td>0.71±0.09</td>
<td>405</td>
</tr>
<tr>
<td>10</td>
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<td>2.99 x 10^{-4}</td>
<td>2.49 x 10^{-5}</td>
<td>2.92 x 10^{-4}</td>
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<td>0.77±0.06</td>
<td>416</td>
</tr>
<tr>
<td>15</td>
<td>1.47 x 10^{-6}</td>
<td>3.5 x 10^{-4}</td>
<td>1.54 x 10^{-5}</td>
<td>1.66 x 10^{-4}</td>
<td>0.17±0.01</td>
<td>0.80±0.04</td>
<td>430</td>
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</tbody>
</table>
Fig. 8. Debye temperature, $\theta_D$, as a function of $\text{Bi}_2\text{O}_3$ content of the $x\text{Bi}_2\text{O}_3$-(20-x)$\text{Li}_2\text{O}$-$2\text{V}_2\text{O}_5$-$60\text{B}_2\text{O}_3$ ($x = 0, 5, 10$ and $15$ mol %) glass samples.

4 Conclusions

The structure and electric conduction of the semiconducting glass system with composition $x\text{Bi}_2\text{O}_3$-(20-x)$\text{Li}_2\text{O}$-$2\text{V}_2\text{O}_5$-$60\text{B}_2\text{O}_3$ ($0 \leq x \leq 15$) mol % are studied in more details.

It is found that the density and molar volume increases with increasing $\text{Bi}_2\text{O}_3$ content. The FT-IR absorption spectra of the investigated glass system have evidenced that boron ions are incorporated as BO$_3$ and BO$_4$ units and a part of bismuth ions are incorporated in the glass network as BiO$_3$ pyramidal and BiO$_5$ octahedral units as well as a part of vanadium ions is incorporated in the glass network as VO$_4$ and VO$_5$ units. With increasing Bi$_2$O$_3$ the BO$_3$ (bridging oxygen ions) converted to BO$_4$ (non-bridging oxygen ions) tetrahedral.

The DC conductivity varied linearly against the reciprocal of temperature at two temperature regions and these observations suggest that the glasses under study show mixed conductivity i.e. electronic as well as ionic.

The Dc conductivity increases at the low temperature region (below Debye temperature) and deceases at high temperature region (above Debye temperature) with increasing Bi$_2$O$_3$ content. Debye temperature increases with increasing Bi$_2$O$_3$ content.

References


